

ABSTRACT

An object of the present invention is to provide a polycrystalline silicon crushed lump in which not only a surface concentration of copper, but also surface concentrations of iron and zinc are low. The polycrystalline silicon crushed lump according to the present invention is a polycrystalline silicon crushed lump having a surface metal concentration of 15.0 pptw or less, in which a copper concentration is 0.30 pptw or less in the surface metal concentration, and a total concentration of iron and zinc is 2.00 pptw or less in the surface metal concentration, and preferably an iron concentration is 1.25 pptw or less, and a zinc concentration is 0.75 pptw or less.

[No Figure]